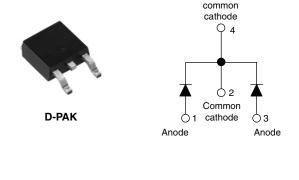


Vishay High Power Products

Schottky Rectifier, 2 x 6 A



Base

PRODUCT SUMMARY			
I _{F(AV)}	2 x 6 A		
V _R	100 V		

FEATURES

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level

DESCRIPTION

The 12CWQ10GPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	12	A		
V _{RRM}		100	V		
I _{FSM}	t _p = 5 μs sine	330	A		
V _F	6 Apk, T _J = 125 °C (per leg)	0.65	V		
TJ	Range	- 55 to 150	۵°		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	12CWQ10GPbF	UNITS	
Maximum DC reverse voltage	V _R	100	V	
Maximum working peak reverse voltage	V _{RWM}	– 100 V		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per leg		50 % duty cycle at T_C = 135 °C, rectangular waveform		6	А
See fig. 5 per device	I _{F(AV)}			12	~
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	330	А
non-repetitive surge current per leg I _{FSM} See fig. 7		10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	110	~
Non-repetitive avalanche energy per leg	E_{AS} T _J = 25 °C, I _{AS} = 1 A, L = 12 mH		6	mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А

* Pb containing terminations are not RoHS compliant, exemptions may apply

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12CWQ10GPbF

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST	VALUES	UNITS	
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	6 A	T 05 %C	0.80	V
		12 A	T _J = 25 °C	0.95	
		6 A	T 105 %C	0.65	
		12 A	— T _J = 125 °C	0.78	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	0.22	mA
See fig. 2	. –	T _J = 125 °C	VR = naleu VR	4	
Threshold voltage	V _{F(TO)}	$T_J = T_J$ maximum		0.47	V
Forward slope resistance	r _t			20.68	mΩ
Typical junction capacitance per leg	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$, (test signal range 100 kHz to 1 MHz) 25 °C		183	pF
Typical series inductance per leg	L _S	Measured lead to lead	5.0	nH	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

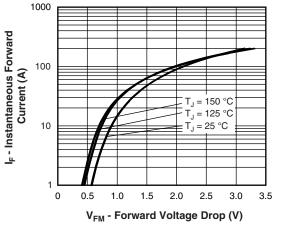
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range Maximum storage temperature range		T _J ⁽¹⁾		55 to 150 °C	•0
		T _{Stg}			
· · · · · · · · · · · · · · · · · · ·	per leg	- Rthuic	DC operation	3.0	°C/W
	per device		See fig. 4	1.5	
Approximate weight				0.3	g
Approximate weight			0.01	oz.	
Marking device			Case style D-PAK (similar to TO-252AA)	12CWQ10G	

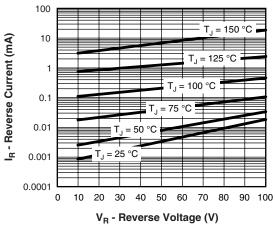
Note

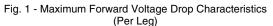
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

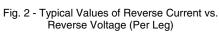


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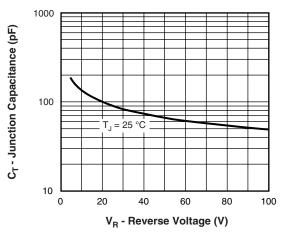


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

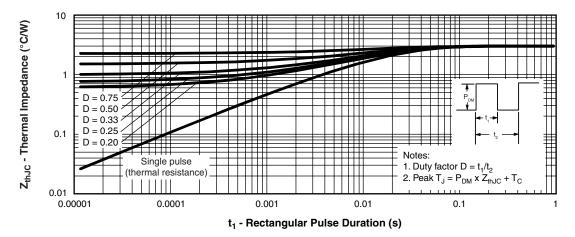


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

12CWQ10GPbF

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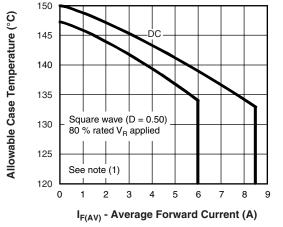


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

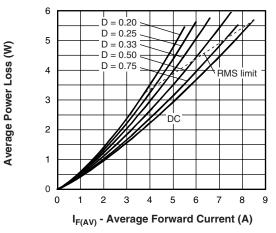


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

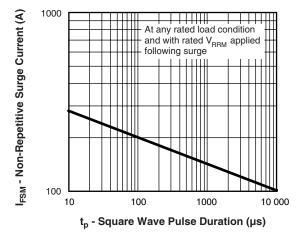


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

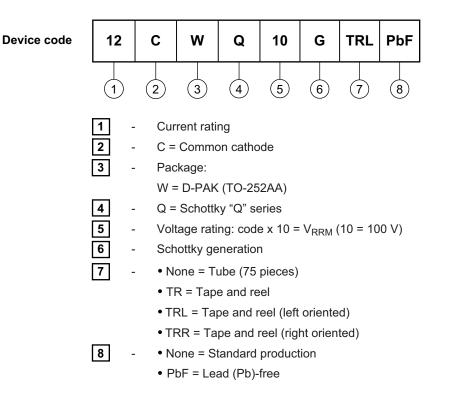
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = 80 \%$ rated V_R



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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95016				
Part marking information	http://www.vishay.com/doc?95059			
Packaging information	http://www.vishay.com/doc?95033			



Vishay

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